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Suite 1000

17950 Preston Road

Dallas, Texas 75252-5793

Phone: 972-732-1001 Facsimile: 972-732-9218

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| To: Examiner Thanh Y. Tran | Total Pages Sent: 5 |
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Haupt Docket No.: INTECH 3.0-104 (2003 P 51718 US)

Serial No: 10/766,053 Art Unit: 2822

Date Filed: January 28, 2004

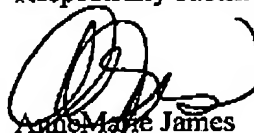
Title: Method for N+ Doping of Amorphous Silicon and Polysilicon Electrodes in Deep Trenches

CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that the following papers are being transmitted by facsimile to the U.S. Patent and Trademark Office at 703-872-9306 on the date shown above:

- Certification of Facsimile Transmission (1 page)
- Petition for Extension of Time Under 37 CFR 1.136(a) (1 original and 1 copy)
- Election (2 pages)

Respectfully submitted,


Anne Marie James
Legal Assistant**RECEIVED**
OICE/IAP**JUN 27 2005****Confirmation Respectfully Requested**

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